

DUAL HIGH SPEED SINGLE SUPPLY OPERATIONAL AMPLIFIER

■FEATURES

- Low Input Offset Voltage 3.5mV max.
- Low Input Offset Voltage Drift 3.5 μ V/ $^{\circ}$ C
- High Slew Rate 8.5V/ μ s
- High Unity Gain Frequency 3.5MHz
- Single Supply 3V~36V
- Operating Temperature Range -40 $^{\circ}$ C~+125 $^{\circ}$ C
- Low input voltage around GND level
- Unity-Gain Stable ($C_L=1000\text{pF}$)
- Operating Current (All amplifiers) 4.3mA
- No Phase Reversal
- High EMI Immunity
- Output Short-Circuit Protection
- Package

NJM842

SOP8, SSOP8, VSP8

■APPLICATIONS

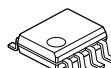
- Current Sensor
- Buffer Application Amplifier
- Active filter
- Battery Application

■GENERAL DESCRIPTION

The NJM842 is a high slew rate, single supply Dual operational amplifier.

The NJM842 is suitable for active filter, buffer, and current control/detect circuits of inverter and motor driver.

■PACKAGE OUTLINE



**NJM842G
(SOP8)**

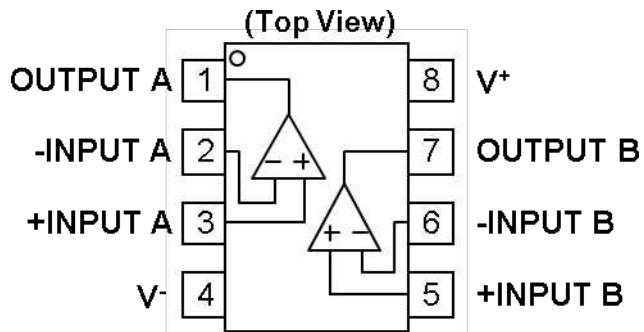


**NJ842V
(SSOP8)**



**NJM842R
(VSP8)**

■PIN CONFIGURATION



**NJM842G
NJM842V
NJM842R**

■ABSOLUTE MAXIMUM RATINGS (Ta=25°C, unless otherwise noted.)

| PARAMETER | SYMBOL | RATING | UNIT |
|--|---------------------------------|---|------|
| Supply Voltage | V ⁺ - V ⁻ | 38 ⁽⁵⁾ | V |
| Differential Input Voltage ⁽¹⁾ | V _{ID} | ±36 ⁽²⁾ | V |
| Input Voltage ⁽²⁾ | V _{IN} | V ⁻ - 0.3 to V ⁺ +36 | V |
| Output Terminal Input Voltage | V _O | V ⁻ - 0.3 to V ⁺ +0.3V | V |
| Power Dissipation ⁽³⁾ | P _D | (2-layer / 4-layer) 780 / 1200 510 / 650 600 / 810 | mW |
| Output Short-Circuit Duration ⁽⁴⁾ | | infinite | |
| Operating Temperature Range | T _{opr} | -40 to +125 | °C |
| Storage Temperature Range | T _{stg} | -55 to +150 | °C |

(1) Differential voltage is the voltage difference between +INPUT and -INPUT.

(2) Input voltage should be allowed to apply to the input terminal independent of the magnitude of V⁺. The normal operation will establish when any input is within the Common Mode Voltage Range of electrical characteristics.

(3) Power dissipation is the power that can be consumed by the IC at Ta=25°C, and is the typical measured value based on JEDEC condition. When using the IC over Ta=25°C subtract the value [mW/°C]=PD/(T_{stg}(MAX)-25) per temperature.

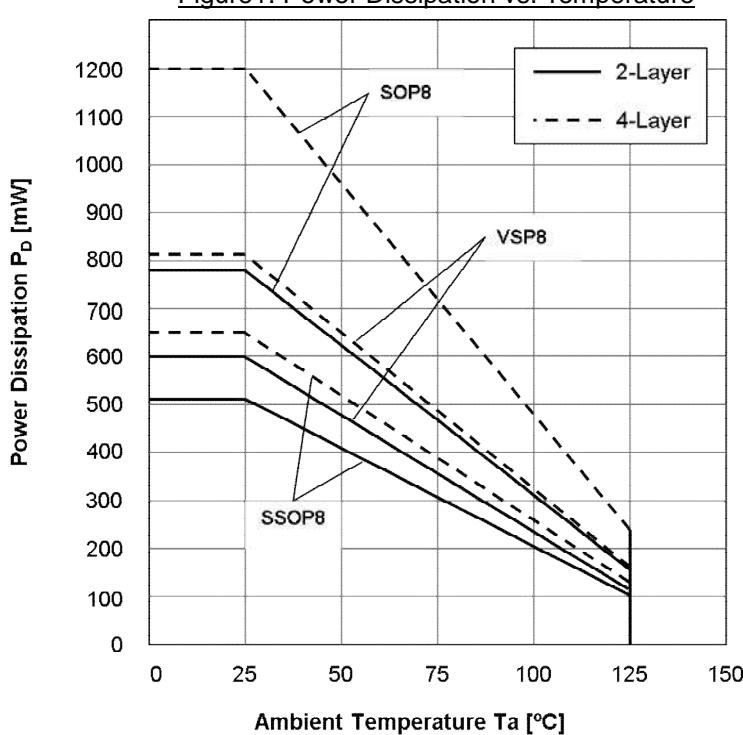
2-layer: EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 2layers, FR-4) mounting

4-layer: EIA/JEDEC STANDARD Test board (76.2x114.3x1.6mm, 4layers, FR-4) mounting

(4) Temperature and/or supply voltages must be limited to ensure the maximum dissipation rating is not exceeded.

(5) Supply Voltage is the voltage difference between V⁺ and V⁻.

Figure1. Power Dissipation vs. Temperature



■RECOMMENDED OPERATING CONDITIONS (Ta=25°C)

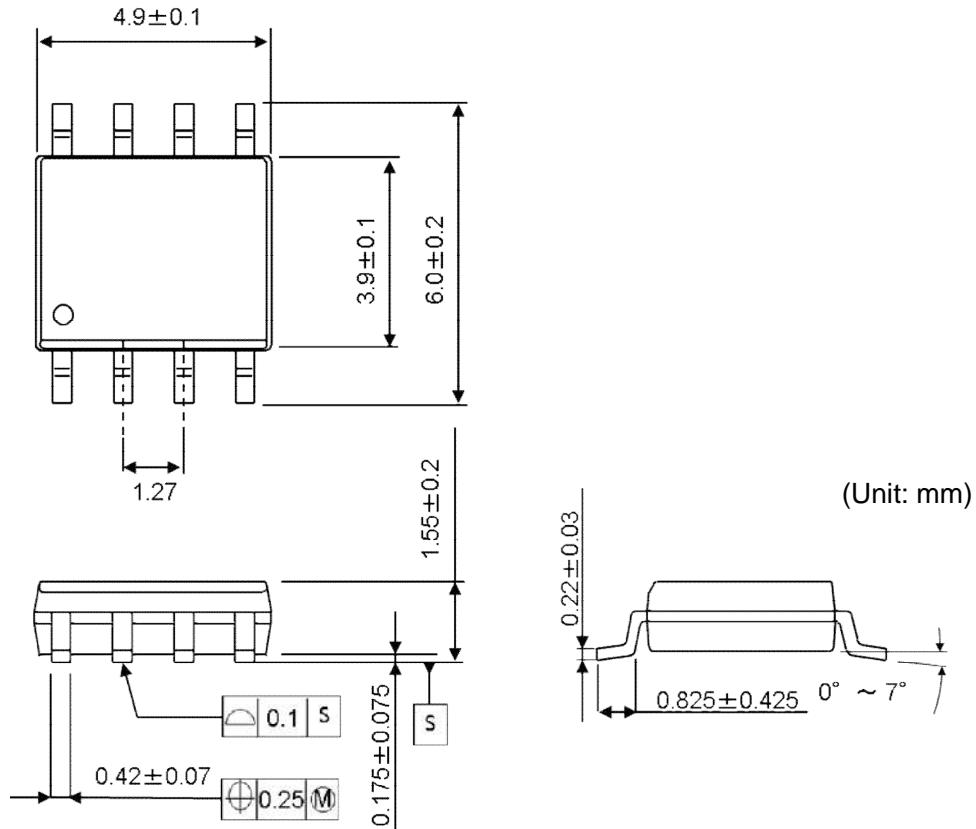
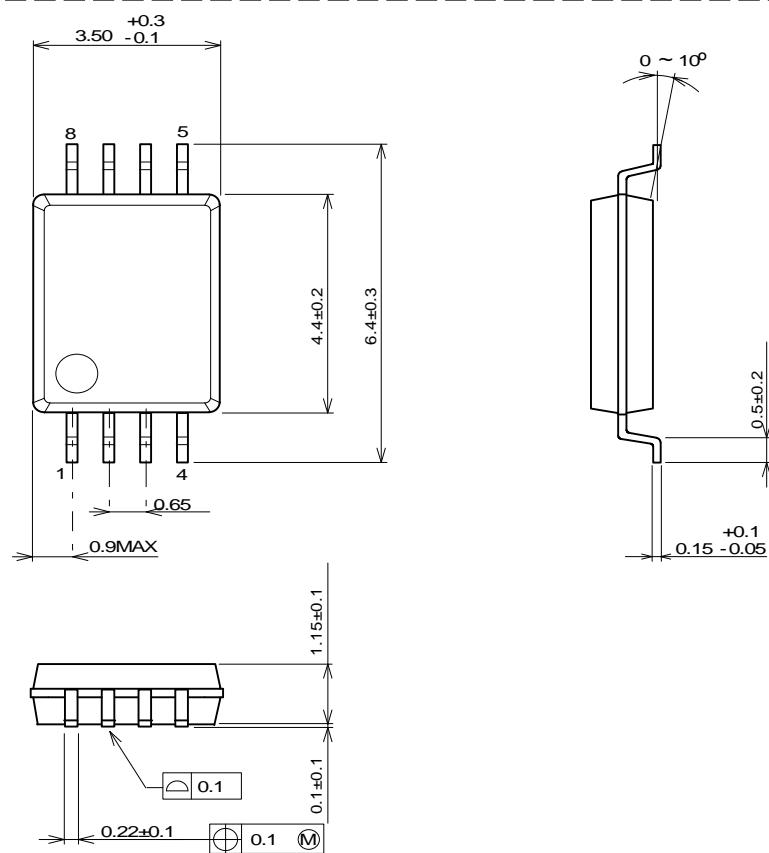
| PARAMETER | Supply Voltage | UNIT |
|----------------|-------------------------|------|
| Supply Voltage | +3 to +36 (±1.5 to ±18) | V |

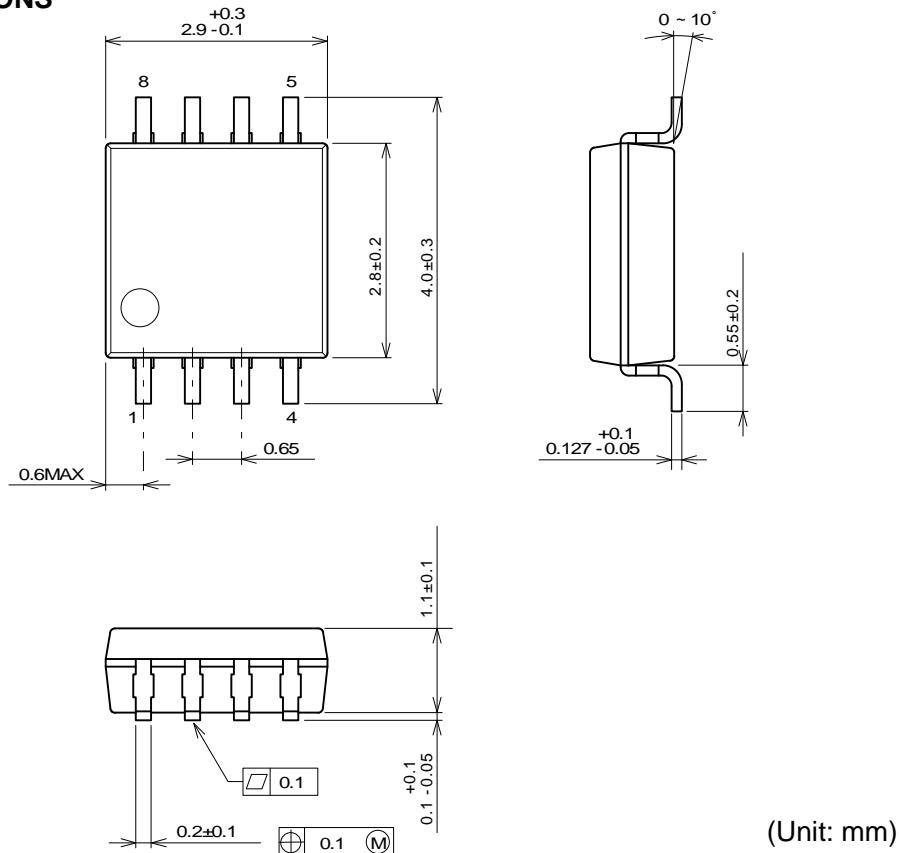
ELECTRICAL CHARACTERISTICS ($V^+=+15V$, $V^-=-15V$, $V_{CM}=0V$, $Ta=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|-----------------------------------|--------------------------|--|-------|-------|-----------|------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Input Offset Voltage | V_{IO} | $R_S=50\Omega$, $V_{CM}=0V$ | - | 0.8 | 3.5 | mV |
| Input Offset Voltage Drift | $\Delta V_{IO}/\Delta T$ | $Ta=-40^\circ C \sim +125^\circ C$ | - | 3.5 | - | $\mu V/^\circ C$ |
| Input Bias Current | I_B | | - | 120 | 500 | nA |
| Input Offset Current | I_{IO} | | - | 6 | 75 | nA |
| Open-Loop Voltage Gain | A_V | $V_o=\pm 10V$, $R_L=2k\Omega$ to $0V$ | 88 | 110 | - | dB |
| Common Mode Rejection Ratio | CMR | $V_{ICM}=-15V$ to $13.2V$ | 70 | 86 | - | dB |
| Common Mode Input Voltage Range | V_{ICM} | CMR ≥ 70 dB | V^- | - | $V^+-1.8$ | V |
| OUTPUT CHARACTERISTICS | | | | | | |
| High-level Output Voltage | V_{OH} | $R_L=10k\Omega$ to $0V$ | 13.7 | 14 | - | V |
| | | $R_L=2k\Omega$ to $0V$ | 13.5 | 14 | - | |
| Low-level Output Voltage | V_{OL} | $R_L=10k\Omega$ to $0V$ | - | -14.3 | -13.7 | V |
| | | $R_L=2k\Omega$ to $0V$ | - | -13.8 | -13.5 | |
| Output Source Current | I_{SOURCE} | $V_o=0V$, +Input = $+1V$, -Input = $0V$ | 10 | 40 | - | mA |
| Output Sink Current | I_{SINK} | $V_o=0V$, +Input = $0V$, -Input = $+1V$ | 10 | 45 | - | mA |
| POWER SUPPLY | | | | | | |
| Supply Current (All amplifiers) | I_{SUPPLY} | No Signal, $R_L=\infty$ | - | 4.3 | 5.5 | mA |
| Supply Voltage Rejection Ratio | SVR | $V^+/V^- = \pm 1.5V$ to $\pm 18V$, $V_{ICM}=0V$ | 70 | 93 | - | dB |
| AC CHARACTERISTICS | | | | | | |
| Gain Bandwidth Product | GBW | $R_L=2k\Omega$ to $0V$, $f=100kHz$ | - | 3.5 | - | MHz |
| Slew Rate | SR | $G_v=0dB$, $R_L=2k\Omega$ to $0V$, $C_L=20pF$, $V_{in}=-10V$ to $+10V$ | - | 8.5 | - | $V/\mu s$ |
| Phase Margin | ϕM | $R_L=2k\Omega$ to $0V$, $C_L=20pF$ | - | 90 | - | deg |
| | | $R_L=2k\Omega$ to $0V$, $C_L=330pF$ | - | 70 | - | |
| Gain Margin | GM | $R_L=2k\Omega$ to $0V$, $C_L=20pF$ | - | 9 | - | dB |
| | | $R_L=2k\Omega$ to $0V$, $C_L=330pF$ | - | 8 | - | |
| NOISE, THD | | | | | | |
| Equivalent Input Noise Voltage | e_n | $f=1kHz$ | - | 32 | - | nV/\sqrt{Hz} |
| Total Harmonic Distortion + Noise | THD+N | $G_v=20dB$, $R_L=2k\Omega$ to $0V$, $C_L=20pF$, $f=1kHz$, $V_o=15V_{PP}$ | - | 0.003 | - | % |
| Channel Separation | CS | $f=10kHz$, Equivalent Input value | - | 120 | - | dB |

ELECTRICAL CHARACTERISTICS ($V^+=+5V$, $V^-=0V$, $V_{CM}=2.5V$, $T_a=25^\circ C$ unless otherwise noted)

| PARAMETER | SYMBOL | TEST CONDITION | MIN. | TYP. | MAX. | UNIT |
|---------------------------------|--------------------------|---|-------|------|-----------|------------------|
| INPUT CHARACTERISTICS | | | | | | |
| Input Offset Voltage | V_{IO} | $R_S=50\Omega$, $V_{CM}=V^+/2$, $V_O=V^+/2$ | - | 0.5 | 3.5 | mV |
| Input Offset Voltage Drift | $\Delta V_{IO}/\Delta T$ | $T_a=-40^\circ C \sim +125^\circ C$ | - | 2.5 | - | $\mu V/^\circ C$ |
| Input Bias Current | I_B | $V_{CM}=V^+/2$, $V_O=V^+/2$ | - | 140 | 500 | nA |
| Input Offset Current | I_{IO} | $V_{CM}=V^+/2$, $V_O=V^+/2$ | - | 6 | 75 | nA |
| Open-Loop Voltage Gain | A_V | $V_O=1.5V$ to $3.5V$, $R_L=2k\Omega$ to $0V$ | 88 | 110 | - | dB |
| Common Mode Rejection Ratio | CMR | $V_{CM}=0V$ to $3.2V$ | 70 | 80 | - | dB |
| Common Mode Input Voltage Range | V_{ICM} | CMR ≥ 70 dB | V^- | - | $V^+-1.8$ | V |
| OUTPUT CHARACTERISTICS | | | | | | |
| High-level Output Voltage | V_{OH} | $R_L=2k\Omega$ to $0V$ | 3.7 | 4 | - | V |
| Low-level Output Voltage | V_{OL} | $R_L=2k\Omega$ to $0V$ | - | 0 | 0 | V |
| Output Source Current | I_{SOURCE} | $V_O=0V$, +Input=+1V, -Input=0V | 10 | 30 | - | mA |
| Output Sink Current | I_{SINK} | $V_O=5V$, +Input=0V, -Input=+1V | 10 | 30 | - | mA |
| POWER SUPPLY | | | | | | |
| Supply Current (All amplifier) | I_{SUPPLY} | No Signal, $R_L=\infty$ | - | 3.3 | 4.5 | mA |
| AC CHARACTERISTICS | | | | | | |
| Gain Bandwidth Product | GBW | $R_L=2k\Omega$ to $0V$, $f=100kHz$ | - | 3.5 | - | MHz |
| Slew Rate | SR | $G_V=0dB$, $R_L=2k\Omega$ to $0V$, $C_L=20pF$, $V_{IN}=+0.5V$ to $+3V$ | - | 7 | - | $V/\mu s$ |
| Phase Margin | ϕM | $R_L=2k\Omega$ to $0V$, $C_L=20pF$ | - | 80 | - | deg |
| | | $R_L=2k\Omega$ to $0V$, $C_L=330pF$ | - | 55 | - | |
| Gain Margin | GM | $R_L=2k\Omega$ to $0V$, $C_L=20pF$ | - | 9 | - | dB |
| | | $R_L=2k\Omega$ to $0V$, $C_L=330pF$ | - | 7 | - | |
| NOISE, THD | | | | | | |
| Equivalent Input Noise Voltage | e_n | $f=1kHz$ | - | 30 | - | nV/\sqrt{Hz} |

■PACKAGE DIMENSIONS**SOP8 Package****SSOP8 Package**

■PACKAGE DIMENSIONS**MSOP8 (TVSP8) JEDEC MO-187-DA / thin type Package****[CAUTION]**

The specifications on this data book are only given for information, without any guarantee as regards either mistakes or omissions. The application circuits in this data book are described only to show representative usages of the product and not intended for the guarantee or permission of any right including the industrial rights.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NJR:

[NJM842G-TE2](#) [NJM842V-TE1](#) [NJM842R-TE1](#)



**Стандарт
Электрон
Связь**

Мы молодая и активно развивающаяся компания в области поставок электронных компонентов. Мы поставляем электронные компоненты отечественного и импортного производства напрямую от производителей и с крупнейших складов мира.

Благодаря сотрудничеству с мировыми поставщиками мы осуществляем комплексные и плановые поставки широчайшего спектра электронных компонентов.

Собственная эффективная логистика и склад в обеспечивает надежную поставку продукции в точно указанные сроки по всей России.

Мы осуществляем техническую поддержку нашим клиентам и предпродажную проверку качества продукции. На все поставляемые продукты мы предоставляем гарантию .

Осуществляем поставки продукции под контролем ВП МО РФ на предприятия военно-промышленного комплекса России , а также работаем в рамках 275 ФЗ с открытием отдельных счетов в уполномоченном банке. Система менеджмента качества компании соответствует требованиям ГОСТ ISO 9001.

Минимальные сроки поставки, гибкие цены, неограниченный ассортимент и индивидуальный подход к клиентам являются основой для выстраивания долгосрочного и эффективного сотрудничества с предприятиями радиоэлектронной промышленности, предприятиями ВПК и научно-исследовательскими институтами России.

С нами вы становитесь еще успешнее!

Наши контакты:

Телефон: +7 812 627 14 35

Электронная почта: sales@st-electron.ru

Адрес: 198099, Санкт-Петербург,
Промышленная ул, дом № 19, литер Н,
помещение 100-Н Офис 331